

Form PTO 1449
(Modified)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

ATTY DOCKET NO.

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SERIAL NO.

10/549,364

LIST OF REFERENCES CITED BY APPLICANT

APPLICANT

Makoto ISHIDA, et al.

FILING DATE

July 17, 2006

GROUP

2826

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
					YES	NO
	AO					
	AP					
	AQ					
	AR					
	AS					
	AT					
	AU					
	AV					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

	AW	D. AKAI ET AL, Science d Direct, "Epitaxial Growth of Pt(001) thin films on Si substrates using an epitaxial γ -Al ₂ O ₃ (001) buffer layer, Journal of Crystal Growth 264 (2004) 463-467
	AX	D. AKAI, APPLIED PHYSICS LETTERS 86, 202906 (2005), Ferroelectric properties of sol-gel delivered epitaxial Pb(Zr _x , Ti _{1-x})O ₃ THIN FILMS ON SI USING EPITAXIAL γ -Al ₂ O ₃ Layers
	AY	
	AZ	

☐ Additional References sheet(s) attached

Examiner /Kevin Quinto/

Date Considered 04/11/2008

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /KQ/